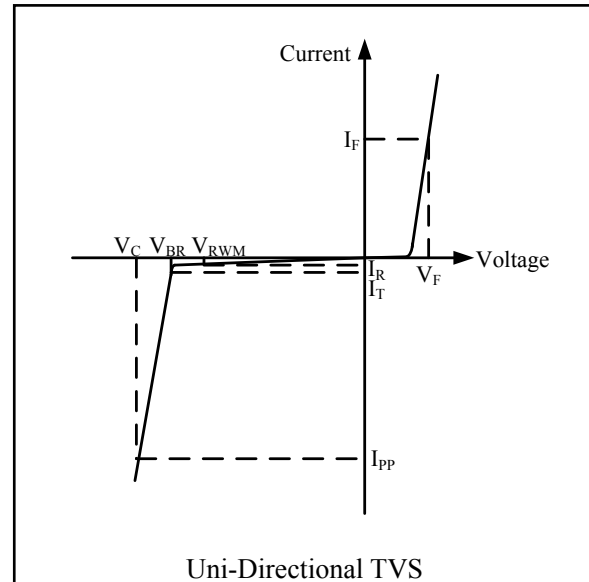


Absolute Maximum Rating

Symbol	Parameter	Value	Units
I_{PP}	Peak Pulse Current (8/20 μ s)	18	A
P_{PK}	Peak Pulse Power (8/20 μ s)	350	Watts
V_{ESD}	ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	± 30 ± 30	kV
T_{OPT}	Operating Temperature	-55/+125	$^{\circ}$ C
T_{STG}	Storage Temperature	-55/+150	$^{\circ}$ C

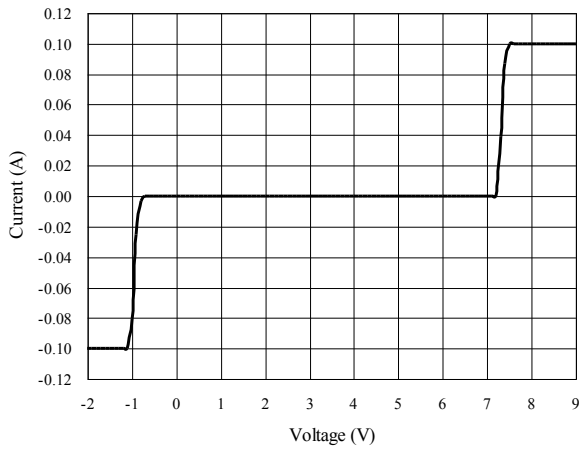
Electrical Characteristics (T = 25 $^{\circ}$ C)

Symbol	Parameter
V_{RWM}	Nominal Reverse Working Voltage
I_R	Reverse Leakage Current @ V_{RWM}
V_{BR}	Reverse Breakdown Voltage @ I_T
I_T	Test Current for Reverse Breakdown
V_C	Clamping Voltage @ I_{PP}
I_{PP}	Maximum Peak Pulse Current
C_{ESD}	Parasitic Capacitance
V_R	Reverse Voltage
f	Small Signal Frequency
I_F	Forward Current
V_F	Forward Voltage @ I_F

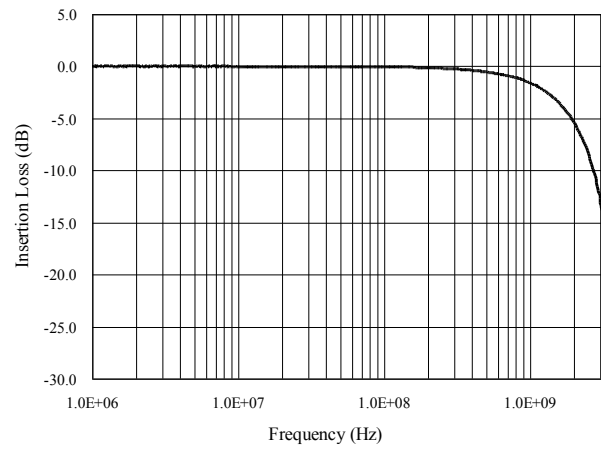


Symbol	Test Condition	Minimum	Typical	Maximum	Units
V_{RWM}				5.0	V
I_R	$V_{RWM} = 5V, T = 25^{\circ}C$ Between I/O and GND		0.1	1.0	μ A
V_{BR}	$I_T = 1mA$ Between I/O and GND	6.0	7.0	9.0	V
V_F	$I_F = 15mA$			1.2	V
V_C	$I_{PP} = 1A, t_p = 8/20\mu s$ Between I/O and GND			12	V
V_C	$I_{PP} = 5A, t_p = 8/20\mu s$ Between I/O and GND			17	V
C_{ESD}	$V_R = 0V, f = 1MHz$ Between I/O and GND		3.5	5.0	pF
C_{ESD}	$V_R = 0V, f = 1MHz$ Between I/O and I/O		1.5	2.5	pF

Voltage Sweeping of I/O to GND

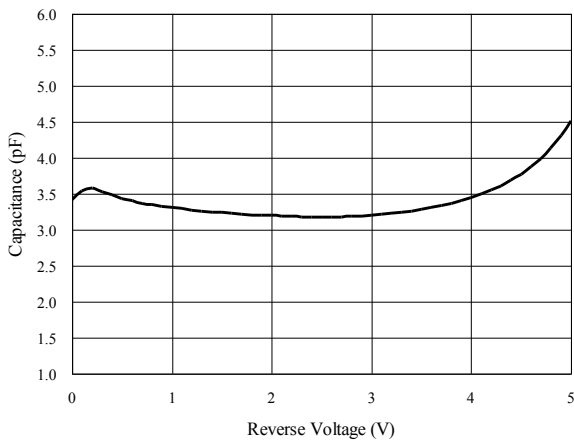


Insertion Loss S21 of I/O to GND

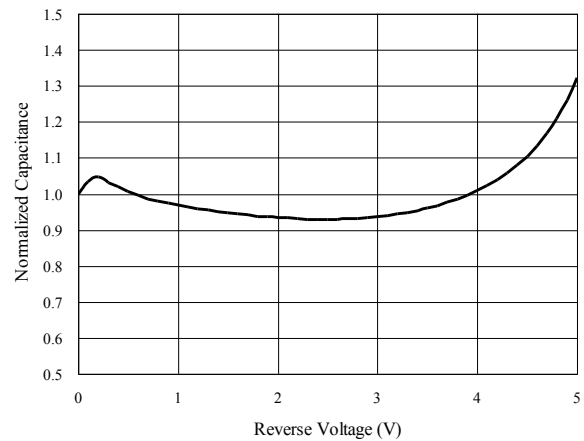


Capacitance vs. Voltage of I/O to GND (f = 1MHz)

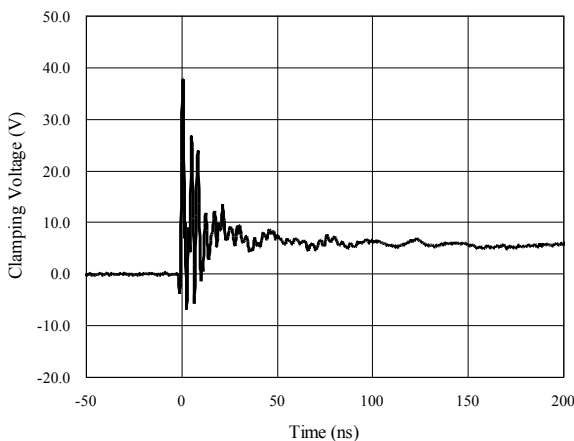
Capacitance vs. Reverse Voltage



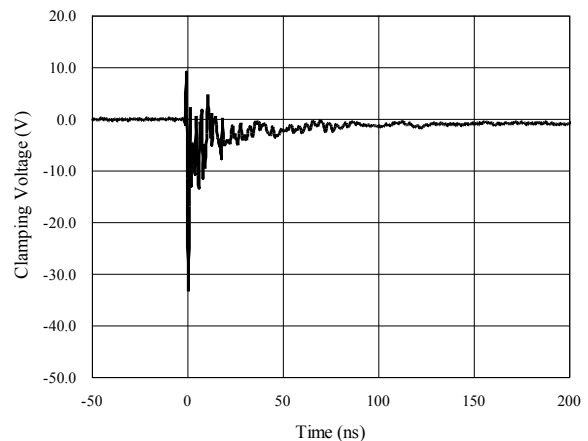
Normalized Capacitance vs. Reverse Voltage



ESD Clamping of I/O to GND (+8kV Contact per IEC 61000-4-2)

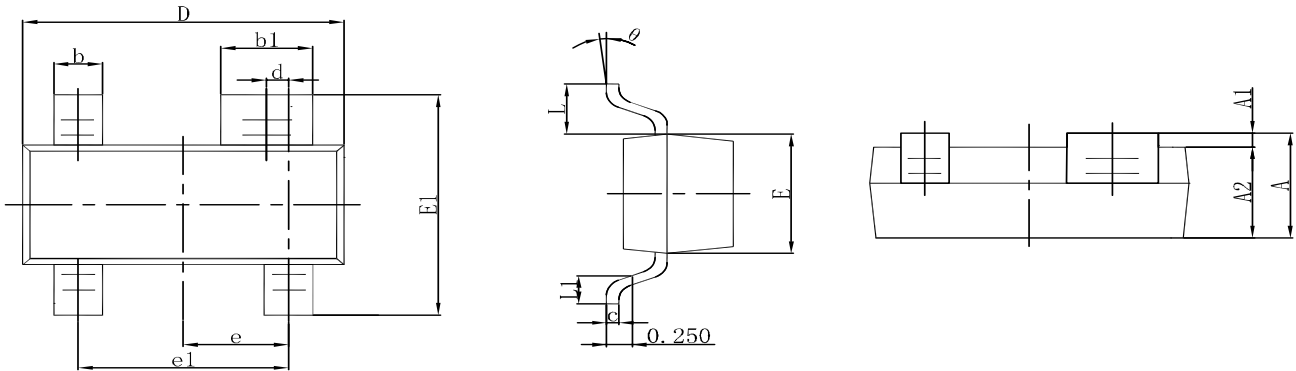


ESD Clamping of I/O to GND (-8kV Contact per IEC 61000-4-2)



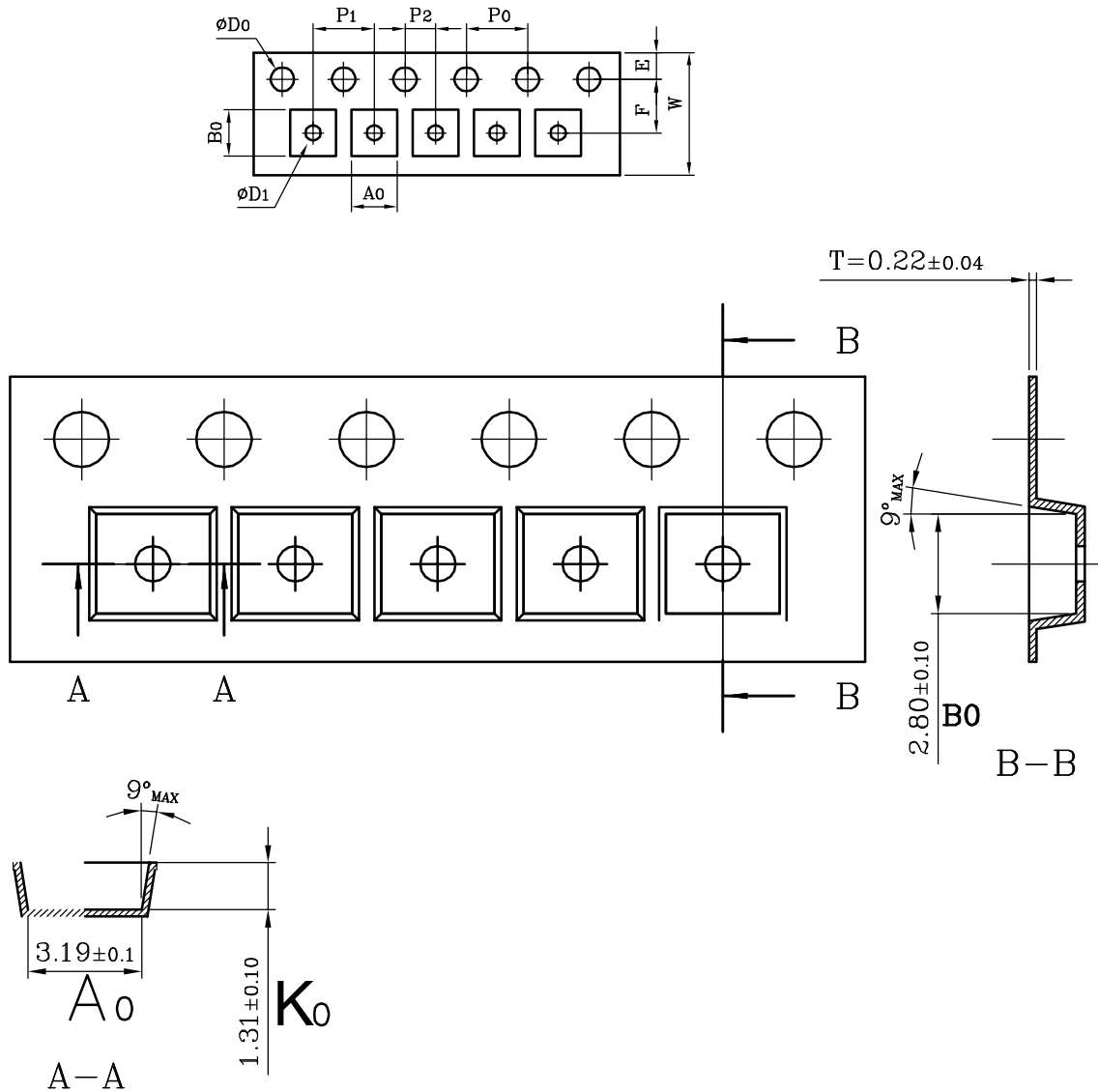
Package Outline

□ SOT-143 package



Symbol	Dimensions in millimeter		Dimensions in Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
b1	0.750	0.900	0.030	0.035
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
d	0.200 TYP.		0.008 TYP.	
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.550 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

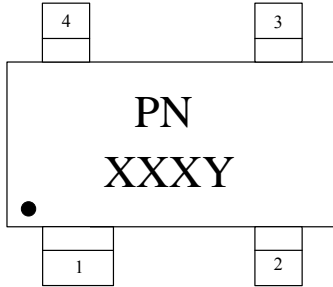
Tape and Reel Specification



(UNIT:mm)

Symbol	W	P1	E	F	D0	D1	P0	P2	10P0
Dimensions	$8.00^{+0.30}_{-0.10}$	4.0 ± 0.1	1.75 ± 0.1	3.5 ± 0.10	$1.5^{+0.10}_{-0}$	$1.0^{+0.10}_{-0.05}$	4.0 ± 0.1	2 ± 0.05	40 ± 0.2
Symbol	A0	A1	B0	B1	K0	K1	T		
Dimensions	3.19 ± 0.10		2.80 ± 0.10		1.31 ± 0.10		0.22 ± 0.04		

Marking Codes



Note:

- (1) PN is "S2M", and is part number, fixed.
- (2) "XXX" is the last 3 characters of the wafer's Lot No.,
 "Y" is the internal code.

Ordering Information

Part Number	Working Voltage	Quantity Per Reel	Reel Size
TS0512PMX	5V	3,000	7 Inch

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